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OPEN Defects, Dopants and Sodium Mobility in Na₂MnSiO₄

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Sodium manganese orthosilicate, Na₂MnSiO₄, is a promising positive electrode material in rechargeable sodium ion batteries. Atomistic scale simulations are used to study the defects, doping behaviour and sodium migration paths in Na₂MnSiO₄. The most favourable intrinsic defect type is the cation anti-site (0.44 eV/defect), in which, Na and Mn exchange their positions. The second most favourable defect energy process is found to be the Na Frenkel (1.60 eV/defect) indicating that Na diffusion is assisted by the formation of Na vacancies via the vacancy mechanism. Long range sodium paths via vacancy mechanism were constructed and it is confirmed that the lowest activation energy (0.81 eV) migration path is three dimensional with zig-zag pattern. Subvalent doping by Al on the Si site is energetically favourable suggesting that this defect engineering stratergy to increase the Na content in Na₂MnSiO₄ warrants experimental verification.

Sodium ion batteries have attracted attention as a dominant power source in large scale energy storage applications due to the low cost and high abundance of sodium as compared to lithium¹⁻³.

New class of cathode materials providing large quantity of Na ions in sodium batteries can lead to the high power density and high energy density. Several promising sodium based cathode materials such as NaFePO₄⁴⁻⁶, $Na_2FePO_4F^{7,8}$, $Na_3V_2(PO_4)_3^{9,10}$ and Na_xTMO_2 (TM = Ti, V, Cr, Mn, Fe, Co and Ni)¹¹⁻¹³ were reported in the experimental studies. Discovery of novel cathode materials is still active to produce high capacity battery to satisfy the

Orthosilicate Na2MnSiO4 has been recently proposed as a promising Na storage material because of its impressive sodium storage performance, low cost and environmentally benign¹⁴⁻¹⁹. The structural stability of this material is mainly provided by the $(SiO_4)^{4-}$ matrix via strong Si-O bonds. Further, it may be possible to extract more than one sodium more readily from Na₂MnSiO₄ since Mn can form the Mn⁴⁺ oxidation state. Chen et al. 15 synthe sized Na_2MnSiO_4 by a sol-gel method and reported a reversible capacity of 125 mAhg^{-1} at a rate of C/10 using an ionic liquid electrolyte at elevated temperatures. Law et al.14 prepared Na₂MnSiO₄ via a modified two-step route and reported an impressive sodium storage performance of 210 mAhg⁻¹ at 0.1 C. Using first-principles calculations, Zhang et al.¹⁵ investigated ion diffusion mechanism of Na₂MnSiO₄ and concluded that the Na ion diffusion is faster than Li ion diffusion in Li₂MnSiO₄. There are a limited number of experimental and theoretical work reported in the literature.

As experiments cannot provide detailed information about the defects and Na ion diffusion paths with activation energies, classical modelling techniques are widely used to calculate those properties. This theoretical approach has been successfully applied on a wide range of lithium ion battery materials and a few sodium ion battery materials^{20–25}. Very recently, we have applied this simulation technique to examine the defect chemistry, lithium transport and the effect of dopants on lithium vacancy formation on the Li₅FeO₄²⁶, Li₂CuO₂²⁷ and Li₉V₃ $(P_2O_7)_3(PO_4)^{28}$. The present study uses atomistic modeling techniques to calculate the energetics for the formation of defects, solution of trivalent dopants and Na ion diffusion paths in Na₂MnSiO₄.

Results and Discussion

Na₂MnSiO₄ structure. The crystal structure of Na₂MnSiO₄ exhibits a monoclinic crystallographic structure with space group Pn (lattice parameters a = 7.02857 Å, b = 5.60957 Å, c = 5.33391 Å, α = 90.0°, β = 89.7949° and $\gamma = 90^{\circ}$) as reported by Nalbandyan et al. ¹⁶ In the Fig. 1, crystal structure of Na₂MnSiO₄ is shown together with bonding nature of all cations forming corner-sharing tetrahedral units with four O atoms. First, experimental monoclinic crystal structure was reproduced using classical pair potentials as tabulated in Table S1 in the

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Parameter	Calc	Expt ¹³	Δ (%)
a (Å)	6.995595	7.028570	0.47
b (Å)	5.644977	5.609570	0.63
c (Å)	5.334769	5.333910	0.02
α (°)	90.0000	90.0000	0.00
β (°)	89.7683	89.7949	0.03
γ (°)	90.0000	90.0000	0.00

Table 1. Calculated and Experimental Structural Parameters for Monoclinic (Pn) Na₂MnSiO₄.

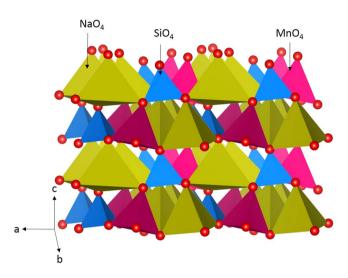


Figure 1. Crystal structure of Na₂MnSiO₄ (space group Pn).

Supplementary Information. There is an excellent agreement between experimental and calculated equilibrium-lattice constants (refer to Table 1).

Intrinsic defect processes. Next we calculated different isolated point defects including vacancies and interstitials to calculate the Frenkel and Schottky-type defect formation energies in Na₂MnSiO₄. These intrinsic defect energetics can provide useful information about the electrochemical behavior of Na₂MnSiO₄. Here we write equations for the Frenkel, Schottky and anti-site defect formation using the Kröger-Vink notation²⁹.

Na Frenkel:
$$Na_{Na}^{X} \rightarrow V_{Na}^{'} + Na_{i}^{\bullet}$$
 (1)

$$\mbox{Mn Frenkel:} \ \mbox{Mn}_{\mbox{Mn}}^{\mbox{X}} \rightarrow \mbox{$V^{''}_{\mbox{Mn}}$} + \ \mbox{Mn}_{\mbox{i}}^{\bullet \bullet} \eqno(2)$$

O Frenkel:
$$O_0^X \rightarrow V_0^{\bullet \bullet} + O_i^{"}$$
 (3)

Si Frenkel:
$$Si_{Si}^X \rightarrow V_{Si}^{''''} + Si_i^{\bullet \bullet \bullet \bullet}$$
 (4)

Schottky: 2 Na
$$_{Na}^{X}$$
 + Mn $_{Mn}^{X}$ + Si $_{Si}^{X}$ + 4 O $_{O}^{X}$ \rightarrow 2 $V_{Na}^{'}$ + $V_{Mn}^{'''}$ + $V_{Si}^{''''}$ + 4 $V_{O}^{\bullet \bullet}$ + Na $_{2}$ MnSiO $_{4}$ (5)

$$Na_2O$$
 Schottky: $2 Na_{Na}^X + O_O^X \rightarrow 2 V_{Na}^{'} + V_O^{\bullet \bullet} + Na_2O$ (6)

MnO Schottky:
$$Mn_{Mn}^{X} + O_{O}^{X} \rightarrow V_{Mn}^{"} + V_{O}^{\bullet \bullet} + MnO$$
 (7)

$$SiO_2$$
 Schottky: $Si_{Si}^X + 2 O_O^X \rightarrow V_{Si}^{""} + 2 V_O^{\bullet \bullet} + SiO_2$ (8)

Na/Mn antisite (isolated): Na
$$_{Na}^{X}+Mn_{Mn}^{X}\rightarrow Na_{Mn}^{'}+Mn_{Na}^{\bullet}$$
 (9)

Migration path	Na-Na separation (Å)	Activation energy (eV)
A	3.2687	0.77
В	3.3041	0.81
С	3.4568	0.98
D	3.2250	0.63

Table 2. Calculated Na-Na separations and activation energies for the sodium ion migration between two adjacent Na sites refer to Fig. 3.

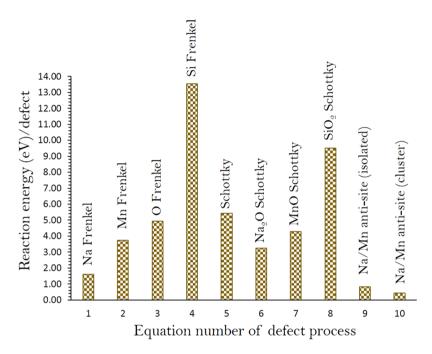


Figure 2. Energetics of intrinsic defect process in monoclinic Na₂MnSiO₄.

Na/Mn antisite (cluster):
$$Na_{Na}^{X} + Mn_{Mn}^{X} \rightarrow \{Na_{Mn}^{'}: Mn_{Na}^{\bullet}\}^{X}$$
 (10)

Figure 2 shows the reaction energies for these intrinsic defect processes (refer to Table S2 for the energies). Na-Mn anti-site was calculated to be the most favorable intrinsic disorder meaning that at high temperatures a small percentage of Na on Mn sites (Na'_{Mn}) and Mn on Na sites (Mn^{\bullet}_{Na}) will be observed. In the relaxed defect structure, a small amount of distortion is observed in the cation-oxygen bond lengths and bond angles, but overall structure of the lattice was not distorted significantly. This type of defect has been observed experimentally in different class of Li ion cathode battery materials during cycling and theoretically in some as prepared Na ion cathode materials^{23–25,30–35}. The Na Frenkel was found to be the second most favourable defect process. The Frenkel and Schottky defect energies were calculated to be highly endothermic meaning that they are unfavorable. The formation enthalpy of Na₂O Schottky (relation 6) is 3.25 eV per defect (refer to Table S2, Supplementary Information). At elevated temperatures, this process can take place to form further V_{Na} and $V_{O}^{\bullet\bullet}$.

Sodium ion-diffusion. The intrinsic sodium ion diffusion of Na₂MnSiO₄ is discussed in this section. Activation energy of Na ion diffusion together with diffusion paths are important when Na₂MnSiO₄ is assessed as a potential material in sodium ion batteries. The current computaional technique enables the calculation of Na diffusion paths together with activation energies, which are diffcult to investigate by experiments. For the Na vacancy migration, four Na local hops (A, B, C and D) were identified. Hop A is between two Na sites with the jump distance of 3.2687 Å and the migration energy is calculated to be 0.77 eV (refer to Table 2). The migration path for hop A is in the ac plane and Na ion moves via a curved trajectory. In the hop B, Na ions diffuses in the ac plane with a curved trajectory but the jump distance of 3.3041 Å and migration energy of 0.81 eV which are different from those calculated for hop A. Hops C and D are in the ab plane with each forming curve trajectories. Their jump distances are 3.4568 Å and 3.3350 Å with corresponding migration energies of 0.98 eV and 0.63 eV respectively. Two possible three dimensional lower energy long range paths $(A \rightarrow B \rightarrow A \rightarrow B)$ and $(C \rightarrow D \rightarrow C \rightarrow D)$ connecting local Na hops were identified as shown in Fig. 3. These two paths exhibited zig-zag pattern with overall activation energies of 0.81 eV and 0.98 eV respectively. We considered other possible long range paths connecting local Na hops. However, the lowest overall activation energy was calculated to be 0.81 eV. Figure 4 reports the energy profile diagrams for Na local hops with activation energies. Zhang et al. 19 calculated the ion diffusion mechanism in Li₂MnSiO₄ and Na₂MnSiO₄ using density functional theory and concluded that Na⁺ migration has relatively lower

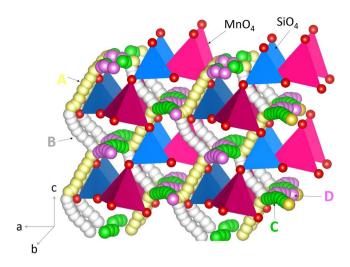


Figure 3. Possible long range sodium vacancy migration paths considered. Local Na migration paths are shown in green, yellow, white and purple atoms. SiO_4 and MnO_4 tetrahedral units are shown blue and pink colors respectively.

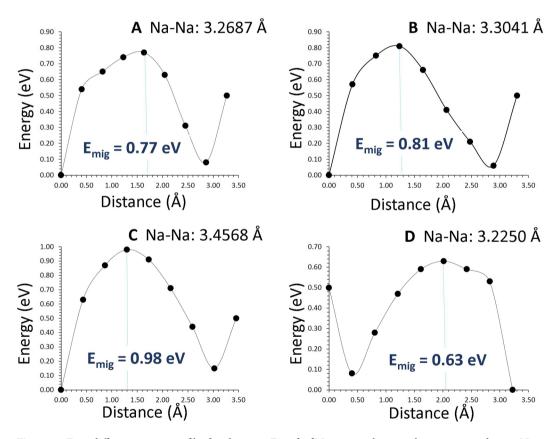


Figure 4. Four different energy profiles [as shown in Fig. 3] of Na vacancy hopping between two adjacent Na sites in Na_2MnSiO_4 .

activation energy barrier than that of Li⁺ migration. In our previous modelling for monoclinic Li₂MnSiO₄, the lowest over all activation energy for Li ion migration is $1.58~{\rm eV^{21}}$. In the current study, the lowest overall Na ion migration barrier is calculated to be $0.81~{\rm eV}$ much lower than that found for Li ion migration in agreement with the study of Zhang *et al.*¹⁹. Furthermore, in their study, Na⁺ ion migrate *via* three dimensional channels and the overall activation energy is calculated to be $0.54~{\rm eV}$. The activation energy difference is due to two different methodologies. Also density functional theory (DFT) is constrained by finite size effects. Small system sizes are a well-known source of error in DFT calculations. Furthermore, in the present study, ions were treated as fully charged as point defects in a highly ionic material might be expected to be in their fully ionic charge states. The position of the highest potential energy along the migration path is defined as the activation energy of migration.

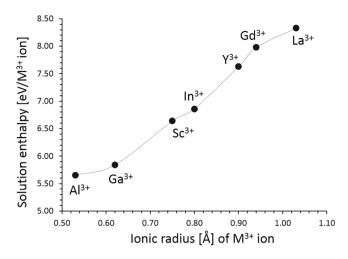


Figure 5. Enthalpy of solution of R_2O_3 (R = Al, Ga, Sc, In, Y, Gd and La) with respect to the R^{3+} ionic radius in Na_2MnSiO_4 .

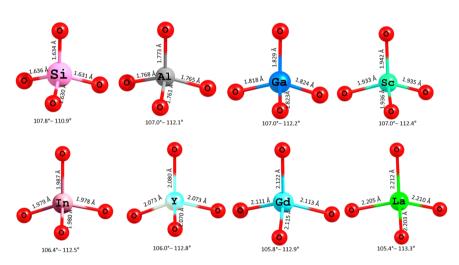


Figure 6. Tetrahedral SiO₄ unit in the relaxed structure of undoped Na₂MnSiO₄ and the coordination formed by the dopants on the Si site with neighbour oxygen.

Trivalent doping. Incorporation of additional sodium into the as-prepared material will enhance the capacity and further increase the applicability of Na_2MnSiO_4 as a potential cathode material for sodium ion batteries. A possible approach to incorporate additional Na is by doping trivalent cations on Si site through creating Na interstitials. Similar approach has been previously demonstrated in Li_2MnSiO_4 cathode material²¹. Here we considered the solution of R_2O_3 (R = Al, Ga, Sc, In, Y, Gd and La) via the following process (in Kröger-Vink notation):

$$R_2O_3 + 2 Si_{Si}^X + Na_2O \rightarrow 2 R_{Si}^{'} + 2 Na_i^{\bullet} + 2 SiO_2$$
 (11)

We report the solution energies of R_2O_3 in Fig. 5. Our calculation reveals that the most favorable dopant solution energy is found for Al^{3+} . This suggests that a possible synthesis-doping strategy of introducing additional sodium into Na_2MnSiO_4 , although the exact amount of Al incorporation cannot be predicted. The possible composition of Al-doped Na_2MnSiO_4 would be $Na_{2+x}MnSi_{1-x}Al_xO_4$ (x=0.0-1.0). The second most favorable dopant is Ga^{3+} . The solution energy increases further with the dopant size.

Figure 6 shows the dopants forming tetrahedral units with adjacent oxygen atoms together with dopant-oxygen bond lengths and oxygen-dopant-oxygen bond angles. For comparison, the tetrahedral SiO₄ unit in the relaxed structure of defect free Na₂MnSiO₄. The ionic radii of Si⁴⁺ and Al³⁺ in tetrahedral coordination are 0.26 Å and 0.39 Å respectively. The ionic radius of Al³⁺ is 0.13 Å larger than that of Si⁴⁺. In the SiO₄ unit, all four Si-O bonds (~1.630 Å) are equal. In AlO₄ unit, Al-O bond lengths (~1.760 Å) and bond angles are slightly larger than that found in SiO₄ unit and smaller than that found in other RO₄ (R = Ga, Sc, In, Y, Gd and La) units. This is reflected in the lowest solution energy for Al. The ionic radius of Ga³⁺ is 0.47 Å slightly larger (by 0.09 Å) than that that of Al³⁺. There is a slight increase in the Ga-O bond lengths and bond angles. This is reflected in the second lowest solution enthalpy. From Sc³⁺ to La³⁺, solution enthalpy steadily increases with ionic radius reflecting in

the bond lengths and bond angles. Highly endothermic solution energy values indicate that they will not occur at low temperatures. At elevated temperatures, this process would become feasible.

Summary. In conclusion, the atomistic simulation techniques were employed to calculate intrinsic defects, sodium ion diffusion paths and trivalent doping in order to assess Na_2MnSiO_4 as a promising sodium battery cathode. The dominant energy defect process is Na-Mn anti-site defect suggesting that there would be small intrinsic concentration of Mn on Na sites at operating temperatures. The long range Na ion diffusion path with lowest migration energy was calculated to be three dimensional with the migration energy of 0.81 eV. Solution energies of R_2O_3 (R=Al, Ga, Sc, In, Y, Gd and La) were calculated to increase extra Na ions in Na_2MnSiO_4 . Our calculation suggests that doping Al^{3+} on Si site is an efficient strategy to increase the Na content in Na_2MnSiO_4 requiring experimental investigation.

Computational methods. In the present study we have used the classical pair potential methodology using the GULP package³⁶. In essence this is based on the Born model for ionic crystals. The interionic interactions are long-range (attractive: Coulombic) and short-range (repulsive: electron-electron repulsion). For the latter we employed well established Buckingham potentials (Table S1, Supplementary Information)^{21,23,37-41}. The relaxation of the atomic positions and lattice parameters was achieved by employing the Broyden-Fletcher-Goldfarb-Shanno (BFGS) algorithm⁴². For the lattice relaxation round defects the Mott-Littleton method⁴³ (inner spherical region larger than 700 ions) immediately. Na was placed and fixed at 7 interstitial positions in a linear route between two vacancy sites (all other ions were allowed to relax). Using this series of calculations the maximum energy corresponds to the activation energy of migration along the route. Here we have employed the full charge ionic model with the calculations in the dilute limit. These are sufficient and will correctly calculate trends in energies, however, defect energies are bound to be overestimated^{44,45}.

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Author Contributions

N.K. performed the calculations. All the authors analyzed and discussed the results and contributed to the writing of the paper.

Additional Information

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